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Supporting Information Finite Temperature Behavior of Carbon Atom Doped Silicon Clusters: Depressed Thermal Stabilities, Co-existing isomers, Reversible Dynamical Pathways and Fragmentation Channels.

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Figure S1. $\delta_{\rm rms}$ values for Si₃C and Si₄ clusters at various finite temperatures.



Figure S2. Short-time (1000 steps) averaged potential energies for Si₄C-a and Si₄C-b clusters



Figure S3. Multi-histograms representing the "density of states" or " probability distribution of potential energies Si_4C -b and Si_7C -a clusters

Figure S3 presents the multi-histograms representing the "density of states" or " probability distribution of potential energies" as a function of temperature for Si₄C–b and Si₇C–a clusters. In case of Si₄C–b, the histogram curve of 300 temperature accesses configurations having energies between 0.05 to 0.38 eV. This energy range has appreciable overlap with curves of 400-800 K temperatures, slight overlap with 1000-1400 K and negligible overlap with the 1600-2000 K curves. On the other hand, in case of Si₇C–a, the curves of 400 K and 600 K have significant overlap with 300 K curve which is accessing the energy states between 0.05 eV-0.4 eV. The histograms of 800 K-1400 K have slight overlap with this energy range, followed by no overlapping with the curves of 1600-2000K. This distribution reaffirms the fact that the starting structure is lost after 800 K and 600 K temperature for Si₄C–b and Si₇C–a clusters, respectively. Additionally, it is noted that the number of energy states acquired by Si₄C–b particularly within 0.05-0.8 eV of energy is much higher as compared to that of Si₇C–a. Also, as the potential energy increases, the histogram curves become more flat and broader for Si₇C–a.



Figure S4. Higher energy conformations of Si_nC clusters with their relative energies (eV) observed at finite temperature



Figure S5. Mean square displacements of atoms in Si_nC clusters at 500, 600 and 800 K temperature.



Figure S6. $\delta_{\rm rms}$ values for the extended trajectories of Si₄C-b and Si₇C-a clusters at 1000 K, 1200 K, 1400 K, 1600 K, 1800 K (RDP-1) and 600 K, 800 K, 1000 K (RDP-1) temperatures, respectively.



Figure S7. Fluctuations of C-Si interatomic distances as a function of time for Si₄C-b and Si₇C-a clusters. The bullet points in the plots represent corresponding C-Si interatomic bond distances of the starting geometry.

Cartesian coordinates of Si _n C (n=3-8) conformations:							
Si ₃ C-a	Si₄C-a						
C 0.000000 0.000000 0.000000 SI 0.000000 0.000000 1.782403 SI 0.487079 0.000000 -1.715046 SI 1.933958 0.000021 0.267538	C0.0000000.0000000.000000Si0.0000000.0000001.796030Si0.0000000.093741-1.793588Si-0.972833-1.795644-0.697398Si0.971922-1.8301540.602769						
Si ₄ C-b	Si₄C-I (b from Figure 4)						
C0.0000000.0000000.000000Si0.0000000.0000001.863407Si1.8276500.000000-0.363540Si-0.4426201.773343-0.363363Si1.4013781.7941351.149999	C-0.5997850.499026-0.330450Si1.5387530.141257-0.212287Si-0.080017-1.1485590.975922Si-1.1187471.0814901.213197Si-0.083485-0.287601-1.835512						
Si4C-II (c from Figure 4)	Si C-III (d from Figure 4)						
C 0.085290 1.113766 -0.538323 Si 1.563371 0.271265 0.019715 Si -0.215510 -1.278763 0.682509 Si -0.955400 0.987957 0.947699 Si -0.428937 -0.456770 -1.419704	C 0.277004 0.216684 0.595519 Si 0.094347 -0.076849 -1.061965 Si -0.427743 0.107599 2.375583 Si 1.560341 1.102902 -2.075557 Si -1.345408 -1.226319 0.507260						
Si₅C-a	Si ₅ C-b						
C0.0000000.0000000.00000SI0.0000000.0000001.86460SI0.9277180.000000-1.61743SI0.635395-1.8131500.16928SI0.6353951.8131500.16928SI2.1913570.0000000.58384	C0.0000000.0000000.000000Si0.0000000.0000001.914461Si1.1712740.000000-1.514361Si0.5857721.8116430.200096Si0.585604-1.8117200.200033Si2.162000-0.0001110.738524						
Si₅C-I (Figure S4)	Si₅C-II (Figure S4)						
C -0.106397 0.149051 0.824737 SI 1.132632 -1.273714 0.162754 SI -1.595721 1.111746 0.096440 SI 1.603084 1.013884 0.657904 SI 0.057699 0.276862 -1.392802 SI -1.152194 -1.192528 0.122990	C 0.008023 -0.218782 1.071393 SI 1.293503 -0.626402 -0.238005 SI -1.274161 -0.324962 -0.468111 SI -0.462919 -1.956330 0.834525 SI 0.306196 1.523084 1.106510 SI 0.133951 1.478178 -1.693125						
Si₀C-a	Si ₆ C-I (b from Figure 8)						
C0.0000000.0000000.000000SI0.0000000.0000002.055769SI1.9343510.0000000.696051SI1.280990-0.568862-1.503966SI-1.057189-0.920260-1.503971SI-1.848859-0.5688630.696103	C 0.066888 1.113209 0.323814 SI 1.165239 1.667501 -1.107486 SI 1.568950 -0.326584 -0.018544 SI 0.388739 -2.328962 0.203860 SI -0.684992 -0.243436 -1.186120 SI -1.777458 1.330645 0.658572						

SI	0.309644 -2.060365 0.440504	SI	-0.679940 -0.584953 1.330394		
Si₀C-II (c from Figure 8)			Si₅C-III (d from Figure 8)		
С	-0.996889 0.081231 0.054174	С	C = -0.082193 = 0.637385 = -0.652488		
SI	0.617148 0.081280 -1.267678	SI	0.176542 - 1.758492 - 0.872734		
SI	1.698599 -1.776425 -0.161190	SI	SI -1.247435 -0.883254 -1.185142		
SI	-0.759700 -1.801022 -0.055423	SI	SI -0.148419 2.359503 0.051494		
SI	-2.134318 1.517646 0.176282	SI	SI 1.185818 -0.726554 -1.350152		
SI	0.279208 2.007940 0.100723	SI	1.298984 0.457678 0.874044		
SI	0.724872 -0.050533 1.224776	SI	-1.211571 0.294350 1.043885		
Si ₇ C-a			Si ₇ C-b		
С	0.000000 0.000000 0.000000	С	0.000000 0.000000 0.000000		
SI	0.000000 0.000000 1.739839	SI	0.000000 0.000000 1.738353		
SI	0.000000 0.311449 -1.842250	SI	0.409665 0.000000 -1.743222		
SI	1.180958 1.498951 0.078564	SI	1.951056 0.464197 0.157717		
SI	3.066102 2.669294 -0.591567	SI	1.137074 0.666121 -3.816800		
SI	0.478646 2.814950 -1.811979	SI	2.719989 -0.716760 -1.933200		
SI	2.471979 3.117379 -3.030983	SI	3.584626 0.915018 -3.396773		
SI	2.322654 0.927042 -2.181402	SI	2.140056 1.883862 -1.802807		
Si ₇ C	C-I (Figure S4)	Si ₇ C	Si ₇ C-II (Figure S4)		
С	0.000000 0.000000 0.000000	С	0.000000 0.000000 0.000000		
Si	0.000000 0.000000 1.739839	Si	0.000000 0.000000 2.053402		
Si	0.000000 0.311449 -1.842250	Si	1.977495 0.000000 0.635373		
Si	1.180958 1.498951 0.078564	Si	0.250688 1.593114 -1.312438		
Si	3.066102 2.669294 -0.591567	Si	Si 0.865761 -0.802495 -1.427258		
Si	0.478646 2.814950 -1.811979	Si	-1.475691 1.401013 0.366326		
Si	2.471979 3.117379 -3.030983	Si	Si -0.833496 2.275228 2.580954		
Si	2.322654 0.927042 -2.181402	Si	0.867436 2.220501 1.048775		
Si ₇ C	C-III (Figure S4)	Si ₈ C	Si ₈ C-a		
С	0.000000 0.000000 0.000000	C	0.000000 0.000000 0.000000		
Si	0.000000 0.000000 1.788803	SI	0.000000 0.000000 1.787863		
Si	0.629104 0.000000 -1.766032	SI	0.000000 0.094597 -1.854562		
Si	0.940861 -1.699445 -0.166599	SI	-1.965298 1.451796 -2.097926		
Si	1.964663 0.705091 0.307208	SI	-1.382527 1.536359 0.243497		
Si	2.725233 -1.339525 1.441943	SI	1.962725 1.455673 -2.097832		
Si	3.108634 -2.993528 2.925757	SI	1.379665 1.539207 0.243319		
Si	1.107196 -3.180165 1.724631	SI	-0.003356 3.491955 0.594089		
		SI	-0.002794 2.857339 -1.736894		
Si ₈ C-b			Si₃C-I (Figure S4)		
С	0.000000 0.000000 0.000000	C	1.121067 0.643310 -1.120416		
SI	0.000000 0.000000 1.814750	Si	2.357378 -0.666777 -1.691305		
SI	0.891500 0.000000 -1.688200	Si	-0.654629 0.084525 -1.417285		

SI SI SI SI SI SI	-0.597869 1.948581 -1.021410 0.273816 2.620452 1.239211	-1.661203 -0.672522 -3.779771 -2.627877 -2.821207 -3.377540	-0.803419 0.335332 0.228627 1.841951 1.387996 -0.406062	Si Si Si Si Si Si	-1.582336-1.790169-0.4488600.654021-1.5049060.323667-1.6811231.973080-0.1679190.6902101.5513160.4080140.9803430.1242872.196511-1.243297-0.0464731.276333
Si ₈ C-II (Figure S4)					
C -0.696634 1.282243 1.435483 Si 0.944606 2.154565 1.607493 Si -1.460541 -1.986586 0.172822 Si -2.195967 0.659732 0.377833 Si 2.038434 -0.367360 -1.459836 Si -0.328514 1.809229 -1.010760 Si 0.757750 -0.033149 1.117644 Si 0.911309 -2.081488 0.108472 Si -0.369156 -0.703305 -1.527565			435483 07493 172822 977833 459836 010760 17644 08472 527565		